

Form PTO-1449

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO.
M122-1017

SERIAL NO. 09/146,839
Filed herewith

LIST OF ART CITED BY APPLICANT
(Use several sheets if necessary)

APPLICANT
Anand Srinivasan et. al.

FILING DATE
Filed herewith

GROUP
Unknown

U.S. PATENT DOCUMENTS

*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
A.M	AA	5,703,404	12/97	Matsuura	257	758	
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Subclass	Translation	
							Yes	No
	AL							
	AM							
	AN							
	AO							
	AP							

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

A.M	AR		ARTICLE: Patrick, W., et. al., "Properties of PECVD O ₂ /TEOS Silicon Dioxide", Proceedings VLSI Science & Tech. 1991, pp. 692-711.
	AS		
	AT		

EXAMINER
ANH D. MAI

DATE CONSIDERED
10/13/99

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.